

Docket No.: 241987US2S



IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

IN RE APPLICATION: Fumitaka ARAI, et al.

SERIAL NO.: 10/648,510

GAU: 2818

EXAMINER: Ho, Tu Tu V.

FILED: August 27, 2003

FOR: NONVOLATILE SEMICONDUCTOR MEMORY DEVICE INCLUDING IMPROVED GATE ELECTRODE

LETTER SUBMITTING REPLACEMENT DRAWING SHEET(S)

COMMISSIONER FOR PATENTS
Alexandria, VA 22313

SIR:

Responsive to the below indicated communication, the following drawing sheets are submitted herewith:

☒ 3 Replacement Drawing Sheets ☐ _____ New Drawing Sheets

☒ Official Action dated October 5, 2004

☐ Notice of Allowance/Issue Fee dated _____

☐ Other dated _____

The changes and/or modifications made include the following:

The attached sheets of drawings include changes to Figs. 4A, 13, and 23-26. These sheets, which include Figs. 4A-4F, 13, and 23-26, replace the original sheets including Figs. 4A-4F, 13, and 23-26.

Respectfully Submitted,

OBLON, SPIVAK, McCLELLAND,
MAIER & NEUSTADT, P.C.

Eckhard H. Kuesters
Registration No. 28,870

Customer Number

22850

Tel. (703) 413-3000
Fax. (703) 413-2220
(OSMMN 06/04)

Surinder Sachar

Registration No. 34,423